

MOSFET - Power: 750 mAmps, 20 Volts

N-Channel SOT-23

MGSF1N02L, MVGSF1N02L

These miniature surface mount MOSFETs low $R_{DS(on)}$ assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are dc-dc converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

Features

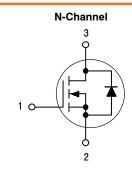
- Low R_{DS(on)} Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- MVGSF Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable*
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_{.I} = 25°C unless otherwise noted)

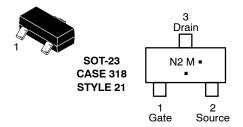
Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	20	Vdc
Gate-to-Source Voltage - Continuous	V _{GS}	± 20	Vdc
Drain Current - Continuous @ T _A = 25°C - Pulsed Drain Current (t _p ≤ 10 μs)	I _D I _{DM}	750 2000	mA
Total Power Dissipation @ T _A = 25°C	P_{D}	400	mW
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to 150	°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	300	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	TL	260	ç

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

750 mAMPS, 20 VOLTS $R_{DS(on)} = 90 \text{ m}\Omega$



MARKING DIAGRAM/ PIN ASSIGNMENT



N2 = Device CodeM = Date Code*= Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation and overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MGSF1N02LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MVGSF1N02LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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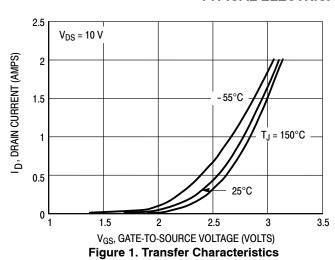
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

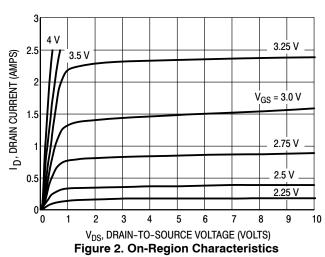
Chara	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS				•	•	
Drain-to-Source Breakdown Voltage ($V_{GS}=0$ Vdc, $I_{D}=10$ μAdc)	V _{(BR)DSS}	20	_	_	Vdc	
Zero Gate Voltage Drain Current ($V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}$) ($V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 12$	I _{DSS}	<u>-</u>	- -	1.0 10	μAdc	
Gate-Body Leakage Current (V _{GS} = :	± 20 Vdc, V _{DS} = 0 Vdc)	I _{GSS}	-	-	±100	nAdc
ON CHARACTERISTICS (Note 1)						
Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 250 \mu Adc$)		V _{GS(th)}	1.0	1.7	2.4	Vdc
Static Drain-to-Source On-Resistance (V_{GS} = 10 Vdc, I_D = 1.2 Adc) (V_{GS} = 4.5 Vdc, I_D = 1.0 Adc)	r _{DS(on)}		0.075 0.115	0.090 0.130	Ω	
DYNAMIC CHARACTERISTICS						
Input Capacitance	(V _{DS} = 5.0 Vdc)	C _{iss}	-	125	-	pF
Output Capacitance	(V _{DS} = 5.0 Vdc)	C _{oss}	-	120	-	
Transfer Capacitance	(V _{DG} = 5.0 Vdc)	C _{rss}	-	45	=	
SWITCHING CHARACTERISTICS (Note 2)					
Turn-On Delay Time		t _{d(on)}	-	2.5	=	ns
Rise Time	(V _{DD} = 15 Vdc, I _D = 1.0 Adc,	t _r	-	1.0	=	
Turn-Off Delay Time	$R_L = 50 \Omega$)	t _{d(off)}	-	16	=	
Fall Time		t _f	-	8.0	-	
Gate Charge (See Figure 6)		Q _T	-	6000	_	рС
SOURCE-DRAIN DIODE CHARACT	ERISTICS					
Continuous Current	I _S	-	-	0.6	Α	
Pulsed Current	I _{SM}	-	-	0.75	-	
Forward Voltage (Note 2)		V_{SD}	-	0.8	-	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 1. Pulse Test: Pulse Width ≤[300 μs, Duty Cycle ≤ 2%.
- 2. Switching characteristics are independent of operating junction temperature.

TYPICAL ELECTRICAL CHARACTERISTICS





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TYPICAL ELECTRICAL CHARACTERISTICS

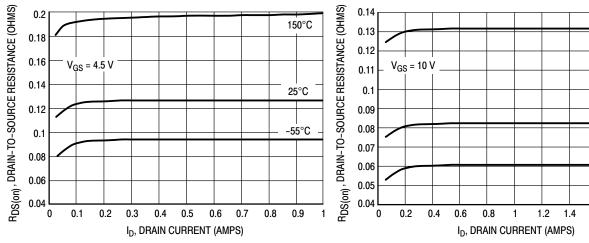


Figure 3. On-Resistance versus Drain Current

Figure 4. On-Resistance versus Drain Current

150°C

25°C

-55°C

1.8

1.6

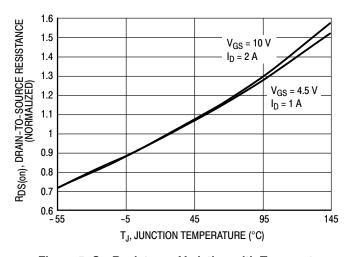


Figure 5. On-Resistance Variation with Temperature

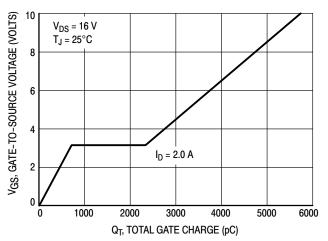


Figure 6. Gate Charge

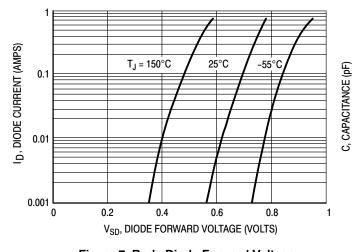


Figure 7. Body Diode Forward Voltage

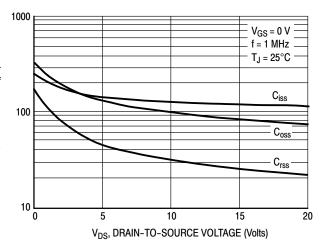


Figure 8. Capacitance

MILLIMETERS

MIN

0.89

0.01

0.37

0.08

2.80

1.20

1.78

0.30

0.35

2.10

O°

NOM

1.00

0.06

0.44

0.14

2.90

1.30

1.90

0.43

0.54

2.40





SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

DATE 14 AUG 2024

MAX

1.11

0.10

0.50

0.20

3.04

1.40

2.04

0.55

0.69

2.64

10°





DETAIL "A" Scale 3:1







NOTES:

DIM

Α

Α1

b

С

D

Ε

е L

L1

HE

Τ

- DIMENSIONING AND TOLERANCING 1. PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS:
- MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

SOT-23 (TO-236) 2.90x1.30x1.00 1.90P CASE 318 ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR			
STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE	2. CATHODE 2.	2: STYLE 13: CATHODE PIN 1. SOURCE CATHODE 2. DRAIN ANODE 3. GATE	STYLE 14: PIN 1. CATHODE 2. GATE 3. ANODE
STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE	STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE	2. ANODE 2.	3: STYLE 19: NO CONNECTION PIN 1. CATHODE CATHODE 2. ANODE ANODE 3. CATHODE-ANODE	STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE
STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT			STYLE 26: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE			

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